Transistors

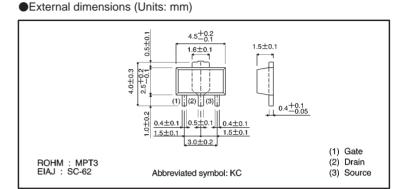
Small switching (60V, 2A) 25K2463

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- 4) Low-voltage drive (4V).
- 5) Easily designed drive circuits.
- 6) Easy to parallel.

Structure

Silicon N-channel MOSFET



Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	60	V
Gate-source voltage		Vgss	±20	V
Drain current	Continuous	lo	2	А
	Pulsed	DP*1	8	А
Reverse drain current	Continuous	ldr	2	А
	Pulsed	DRP*1	8	А
Total power dissipation		Po	0.5 2* ²	W
Channel temperature		Tch	150	Ĉ
Storage temperature		Tstg	-55~+150	Ç

*1 Pw \leq 10 μ s, Duty cycle \leq 1% *2 When mounted on a 40 \times 40 \times 0.7 mm alumina board.

Packaging specifications

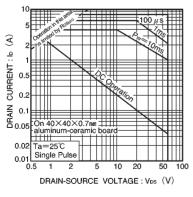
	Package	Taping
Туре	Code	T100
	Basic ordering unit (pieces)	1000
2SK2463		0

Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Gate-source leakage	lgss	—	_	±100	nA	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	V(BR)DSS	60	_	_	V	ID=1mA, VGS=0V
Zero gate voltage drain current	loss	_	_	10	μA	V _{DS} =60V, V _{GS} =0V
Gate threshold voltage	VGS(th)	1.0	_	2.5	V	V _{DS} =10V, I _D =1mA
Static drain-source on-state	5	_	0.30	0.38	Ω	ID=1A, VGS=10V
resistance	RDS(on)	_	0.45	0.58		ID=1A, VGS=4V
Forward transfer admittance	Yfs *	1.2	_	_	S	ID=1A, VDS=10V
Input capacitance	Ciss	_	200	_	pF	V _{DS} =10V
Output capacitance	Coss	_	80	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	50	_	pF	f=1MHz
Turn-on delay time	td(on)		10	_	ns	I⊳=1A, V₀⊳≑30V
Rise time	tr	_	25	_	ns	V _{GS} =10V
Turn-off delay time	td(off)		50	_	ns	RL=30Ω
Fall time	tr	_	50	_	ns	Rg=10Ω
Reverse recovery time	trr	_	70	_	ns	Ibr=2A, Vgs=0V, di/dt=50A/ μ s

* Pw≦300 μs, Duty cycle≦1%

Electrical characteristic curves





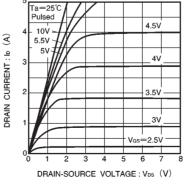
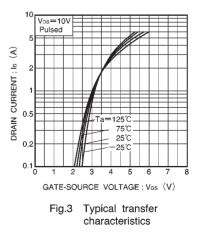
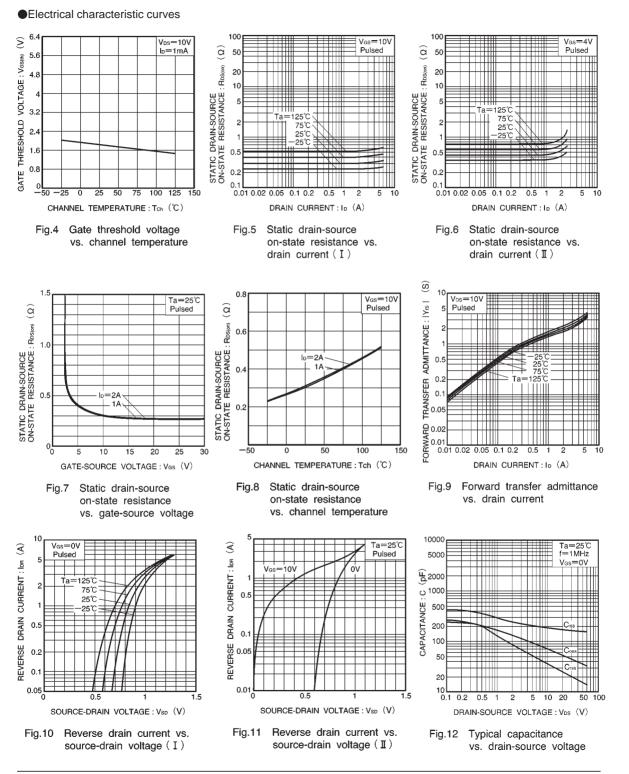
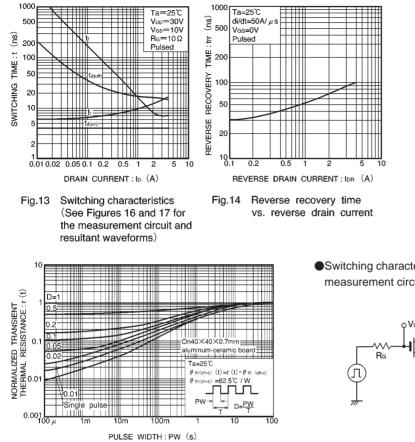


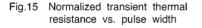
Fig.2 Typical output characteristics



Transistors







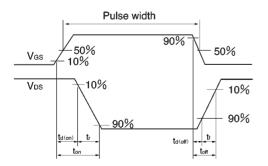


Fig.17 Switching time waveforms

 Switching characteristics measurement circuit

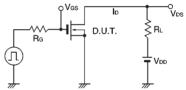


Fig.16 Switching time measurement circuit

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